

100 V - 3 A power Schottky trench diode





Features

- · ST trench process
- · High junction temperature capability
- · Low forward voltage drop
- · Low recovery charges
- · Reduces conduction, reverse and switching losses
- Flat package
- ECOPACK2 compliant

Applications

- · DC/DC converter
- · Auxiliary power supply
- · High switching frequency converter
- Flyback topology
- · Reverse polarity protection
- · Freewheeling function

Description

This 3 A, 100 V rectifier is based on ST trench technology that achieves the best in class V_F/I_R trade-off for a given silicon surface.

Integrated in flat packages, this STPST3H100 trench device is intended to be used in high frequency miniature switched mode power supplies such as adaptors. It is also an ideal candidate for auxiliary power supply in telecom, server, lighting or smart metering and can be the perfect companion device to our VIPer products.



Product status link STPST3H100

Product summary			
I _{F(AV)}	3 A		
V_{RRM}	100 V		
T _j (max.)	175 °C		

0.600 V

V_F (typ.)



1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit
V _{RRM}	Repetitive peak reverse voltage	100	V
I _{F(AV)}	Average forward current, δ = 0.5 square wave	3	Α
I _{FSM}	Surge non repetitive forward current	50	Α
T _{stg}	Storage temperature range	-65 to +175	°C
Tj	Maximum operating junction temperature ⁽²⁾	+175	°C

^{1.} Value based on R_{th(j-l)}(max).

Table 2. Thermal resistance parameter

Symbol	Parameter		Typ. value	Unit	
R _{th(j-l)}	Junction to lead	SOD128Flat	13	°C/W	

For more information, please refer to the following application note:

AN5088: Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
	T _j = 125 °C	V _R = 70 V	-	0.45	1.4	mA	
	T _j = 25 °C	V _R = 100 V	-		5.7	μA	
	T _j = 125 °C		-	0.8	3.0	mA	
		T _j = 25 °C	I _F = 1.5 A	-	0.565	0.625	V
V _F ⁽²⁾ Forward voltage drop	Converd veltage drap	T _j = 125 °C		-	0.500	0.555	
	Forward voltage drop	T _j = 25 °C	I _F = 3 A	-	0.685	0.755	V
		T _j = 125 °C	IF - 3 A	-	0.600	0.650	

^{1.} Pulse test: $t_p = 5 \text{ ms}$, $\delta < 2\%$

To evaluate the conduction losses, use the following equation:

 $P = 0.46 \times I_{F(AV)} + 0.0633 \times I_{F^{2}(RMS)}$

For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

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^{2.} $(dP_{tot}/dT_i) < (1/R_{th(i-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

^{2.} Pulse test: $t_D = 380 \ \mu s, \ \delta < 2\%$



1.1 Characteristics (curves)

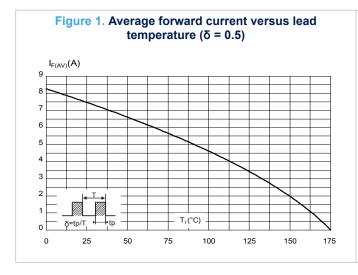


Figure 2. Relative variation of thermal impedance junction to lead versus pulse duration $Z_{th(j-l)}/R_{th(j-l)}$ 0.9 0.7 0.6 0.5 0.2 0.1 0.0 1.E-04 1.E-03 1.E-02 1.E-01 1.E+00 1.E+01

I_R(μA)

1.E+04

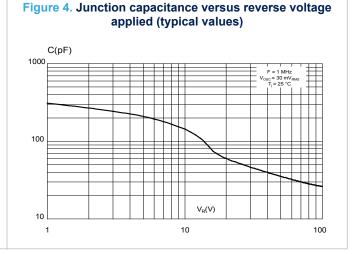
1.E+02

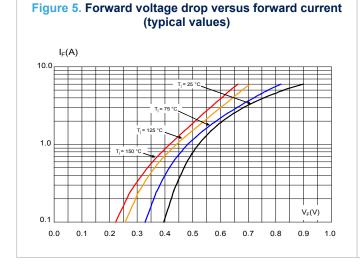
1.E+01

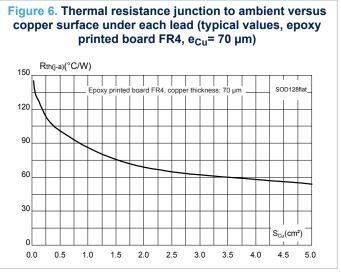
1.E+01

1.E+02

0 10 20 30 40 50 60 70 80 90 100







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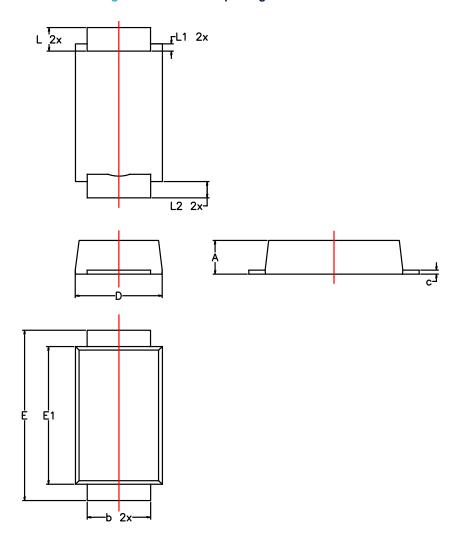
2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 SOD128Flat package information

- Epoxy meets UL94, V0
- Lead-free package

Figure 7. SOD128Flat package outline



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0.018 typ.



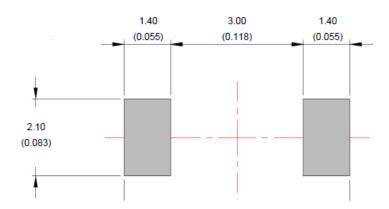
L2

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		Dimensions				
Ref.	Millin	neters	Incl	nches		
	Min.	Max.	Min.	Max.		
Α	0.93	1.03	0.037	0.041		
b	1.69	1.81	0.067	0.071		
С	0.10	0.22	0.004	0.009		
D	2.30	2.50	0.091	0.098		
E	4.60	4.80	0.181	0.189		
E1	3.70	3.90	0.146	0.154		
L	0.55	0.85	0.026	0.033		
L1	0.30	0.30 typ.		typ.		

Table 4. SOD128Flat package mechanical data

Figure 8. SOD128Flat footprint in mm (inches)

0.45 typ.



Note: For package and tape orientation, reel and inner box dimensions and tape outline please check TN1173

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3 Ordering information

Table 5. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPST3H100AF	T3H1	SOD128Flat	26.4 mg	3000	Tape and reel

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Revision history

Table 6. Document revision history

Date	Version	Changes
28-Jan-2021	1	Initial release.

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